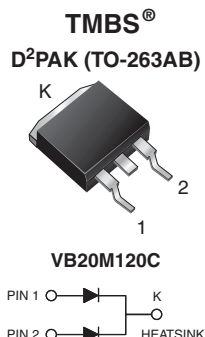


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.55 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS

[click logo to get started](#)

3D
Models
Available

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
V_{RRM}	120 V
I_{FSM}	120 A
V_F at $I_F = 10 \text{ A}$	0.64 V
$T_J \text{ max.}$	150 °C
Package	D ² PAK (TO-263AB)
Circuit configuration	Common cathode

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VB20M120C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	120	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	20	A
		10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	120	
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.65	-	V
	I _F = 10 A			0.82	0.91	
	I _F = 5 A	T _A = 125 °C		0.55	-	
	I _F = 10 A			0.64	0.72	
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	3	-	μA
		T _A = 125 °C		1.5	-	mA
	V _R = 120 V	T _A = 25 °C		-	700	μA
		T _A = 125 °C		4	25	mA

Notes

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 20 \text{ ms}$

**THERMAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	VB20M120C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.8	$^{\circ}\text{C/W}$

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB20M120C-E3/4W	1.37	4W	50/tube	Tube
TO-263AB	VB20M120C-E3/8W	1.37	8W	800/reel	Tape and reel
TO-263AB	VB20M120C-M3/I	1.37	I	800/reel	Tape and reel

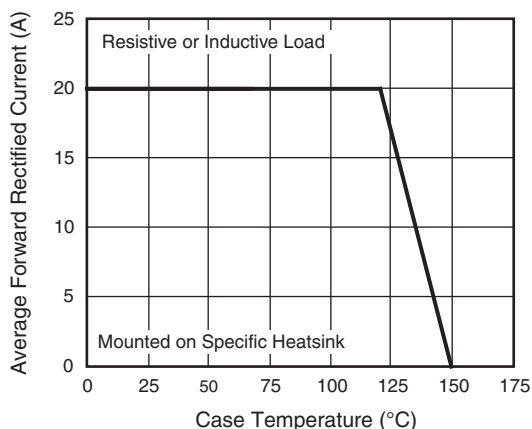
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

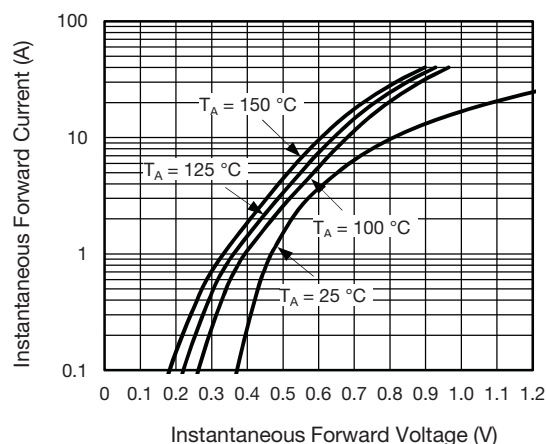


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

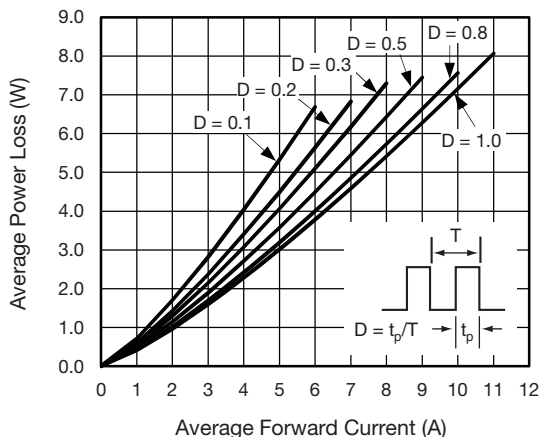


Fig. 2 - Forward Power Loss Characteristics Per Diode

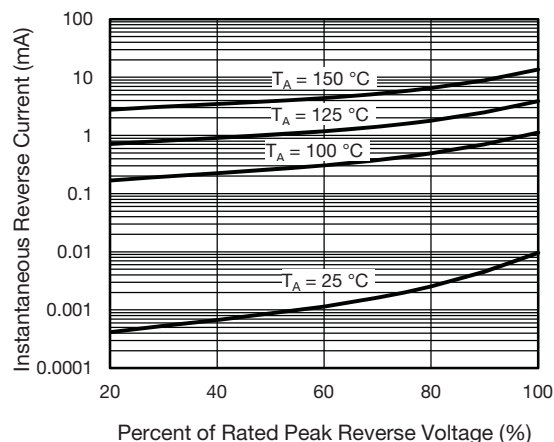


Fig. 4 - Typical Reverse Characteristics Per Diode

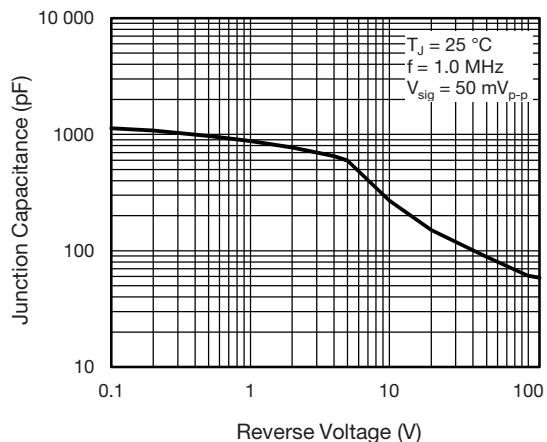


Fig. 5 - Typical Junction Capacitance Per Diode

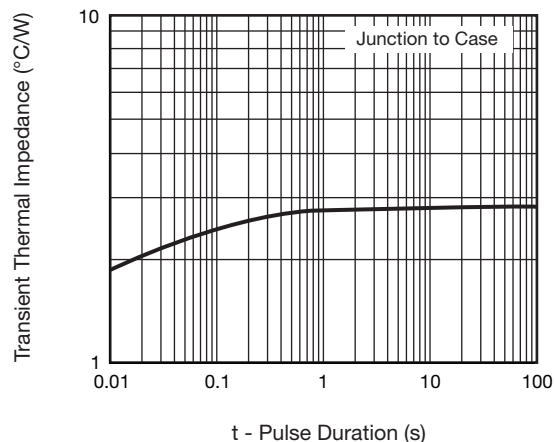
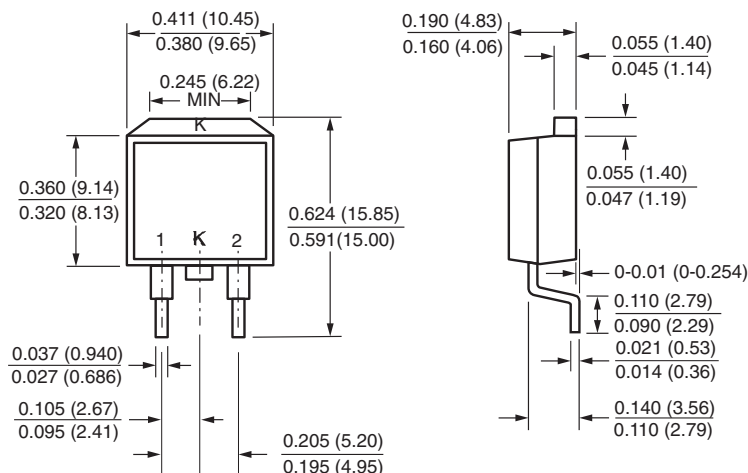
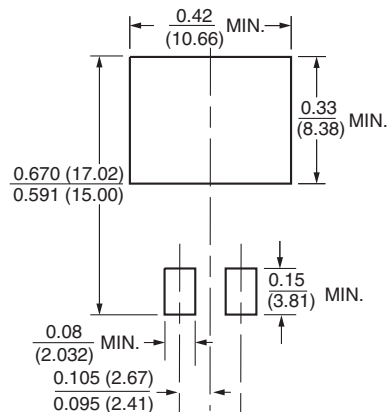


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB)

Mounting Pad Layout




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